

TPH2R003PL

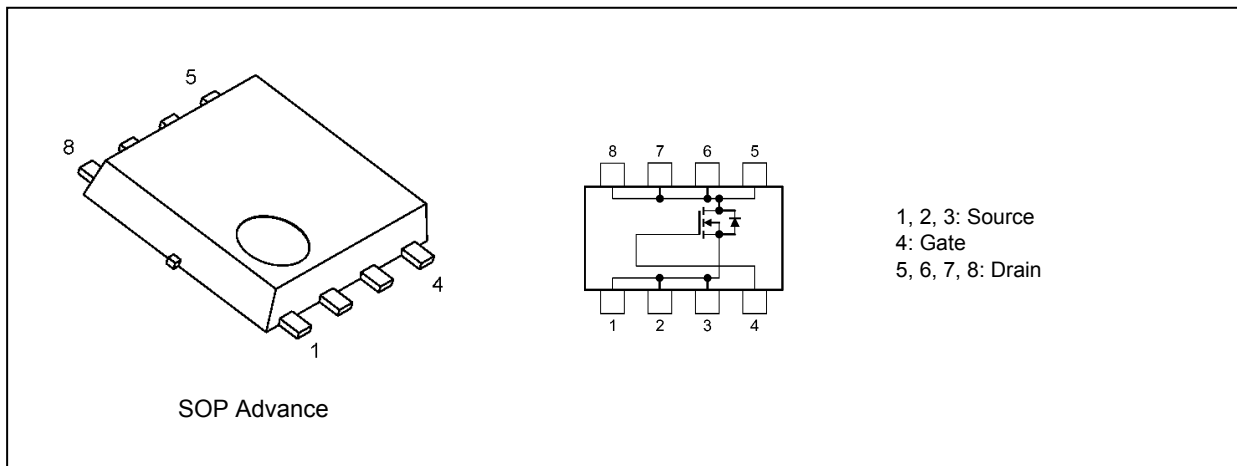
1. Applications

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators
- Motor Drivers

2. Features

- (1) High-speed switching
- (2) Small gate charge: $Q_{SW} = 22 \text{ nC (typ.)}$
- (3) Small output charge: $Q_{OSS} = 41 \text{ nC (typ.)}$
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 1.3 \text{ m}\Omega \text{ (typ.) (} V_{GS} = 10 \text{ V)}$
- (5) Low leakage current: $I_{DSS} = 10 \text{ }\mu\text{A (max) (} V_{DS} = 30 \text{ V)}$
- (6) Enhancement mode: $V_{th} = 1.1 \text{ to } 2.1 \text{ V (} V_{DS} = 10 \text{ V, } I_D = 0.5 \text{ mA)}$

3. Packaging and Internal Circuit



Start of commercial production
2016-07

4. Absolute Maximum Ratings (Note) ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Rating | Unit |
|--|-----------|------------|------------------|
| Drain-source voltage | V_{DSS} | 30 | V |
| Gate-source voltage (Note 1) | V_{GSS} | ± 20 | |
| Drain current (DC) ($T_c = 25\text{ }^\circ\text{C}$) (Note 2) | I_D | 100 | A |
| Drain current (DC) (Silicon limit) (Note 2), (Note 3) | I_D | 180 | |
| Drain current (pulsed) ($t = 100\text{ }\mu\text{s}$) (Note 2) | I_{DP} | 200 | |
| Power dissipation ($T_c = 25\text{ }^\circ\text{C}$) | P_D | 116 | W |
| Power dissipation (Note 4) | P_D | 1.8 | |
| Power dissipation (Note 5) | P_D | 0.83 | |
| Single-pulse avalanche energy (Note 6) | E_{AS} | 92 | mJ |
| Single-pulse avalanche current (Note 6) | I_{AS} | 100 | A |
| Channel temperature | T_{ch} | 175 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to 175 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|---|----------------|------|--------------------|
| Channel-to-case thermal resistance ($T_c = 25\text{ }^\circ\text{C}$) | $R_{th(ch-c)}$ | 1.29 | $^\circ\text{C/W}$ |
| Channel-to-ambient thermal resistance ($T_a = 25\text{ }^\circ\text{C}$) (Note 4) | $R_{th(ch-a)}$ | 83 | |
| Channel-to-ambient thermal resistance ($T_a = 25\text{ }^\circ\text{C}$) (Note 5) | $R_{th(ch-a)}$ | 180 | |

Note 1: +20 V/-16 V ensured at DC condition.

-20 V ensured at pulse condition (duty 5 %).

Note 2: Ensure that the channel temperature does not exceed 175 $^\circ\text{C}$.

Note 3: Limited 100 A by package capability.

Note 4: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 5: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 6: $V_{DD} = 24\text{ V}$, $T_{ch} = 25\text{ }^\circ\text{C}$ (initial), $L = 7.1\text{ }\mu\text{H}$, $I_{AS} = 100\text{ A}$

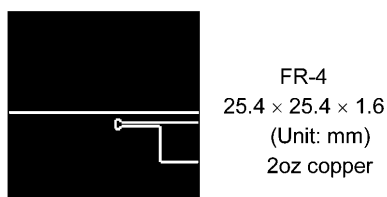


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

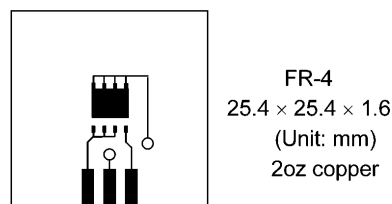


Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---------------|---|-----|------|-----------|------------------|
| Gate leakage current | I_{GSS} | $V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$ | — | — | ± 0.1 | μA |
| Drain cut-off current | I_{DSS} | $V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}$ | — | — | 10 | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$ | 30 | — | — | V |
| Drain-source breakdown voltage (Note 7) | $V_{(BR)DSX}$ | $I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$ | 15 | — | — | |
| Gate threshold voltage | V_{th} | $V_{DS} = 10\text{ V}, I_D = 0.5\text{ mA}$ | 1.1 | — | 2.1 | |
| Drain-source on-resistance | $R_{DS(ON)}$ | $V_{GS} = 4.5\text{ V}, I_D = 50\text{ A}$ | — | 1.7 | 2.6 | $\text{m}\Omega$ |
| | | $V_{GS} = 10\text{ V}, I_D = 50\text{ A}$ | — | 1.3 | 2.0 | |

Note 7: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|-----------|---|-----|------|------|-------------|
| Input capacitance | C_{iss} | $V_{DS} = 15\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$ | — | 4930 | 6410 | pF |
| Reverse transfer capacitance | C_{rss} | | — | 135 | 245 | |
| Output capacitance | C_{oss} | | — | 1455 | — | |
| Gate resistance | r_g | — | — | 1.0 | 1.5 | Ω |
| Switching time (rise time) | t_r | See Figure 6.2.1 | — | 8.2 | — | ns |
| Switching time (turn-on time) | t_{on} | | — | 23 | — | |
| Switching time (fall time) | t_f | | — | 8.6 | — | |
| Switching time (turn-off time) | t_{off} | | — | 49 | — | |

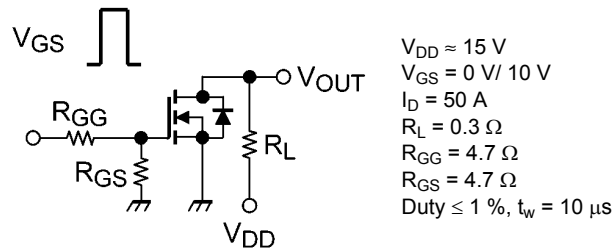


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Q_g | $V_{DD} \approx 15\text{ V}, V_{GS} = 10\text{ V}, I_D = 50\text{ A}$ | — | 86 | — | nC |
| | | $V_{DD} \approx 15\text{ V}, V_{GS} = 4.5\text{ V}, I_D = 50\text{ A}$ | — | 41 | — | |
| Gate-source charge 1 | Q_{gs1} | $V_{DD} \approx 15\text{ V}, V_{GS} = 10\text{ V}, I_D = 50\text{ A}$ | — | 19 | — | |
| Gate-drain charge | Q_{gd} | | — | 12 | — | |
| Gate switch charge | Q_{sw} | | — | 22 | — | |
| Output charge | Q_{oss} | $V_{DS} = 15\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$ | — | 41 | — | |

6.4. Source-Drain Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|------|------|
| Reverse drain current (pulsed) (Note 8) | I_{DRP} | ($t = 100\text{ }\mu\text{s}$) | — | — | 200 | A |
| Diode forward voltage | V_{DSF} | $I_{DR} = 100\text{ A}$, $V_{GS} = 0\text{ V}$ | — | — | -1.2 | V |
| Reverse recovery time | t_{rr} | $V_R = 15\text{ V}$, $I_{DR} = 25\text{ A}$, $V_{GS} = 0\text{ V}$, $-dI_{DR}/dt = 100\text{ A}/\mu\text{s}$ | — | 44 | — | ns |
| Reverse recovery charge | Q_{rr} | | — | 43 | — | nC |

Note 8: Ensure that the channel temperature does not exceed $175\text{ }^\circ\text{C}$.

7. Marking

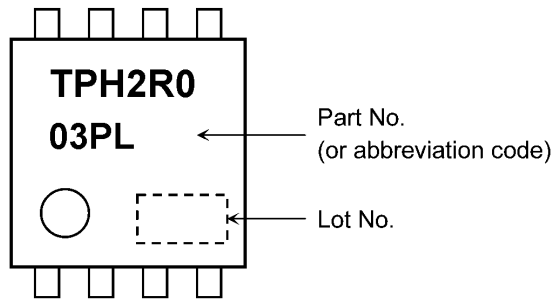


Fig. 7.1 Marking

8. Characteristics Curves (Note)

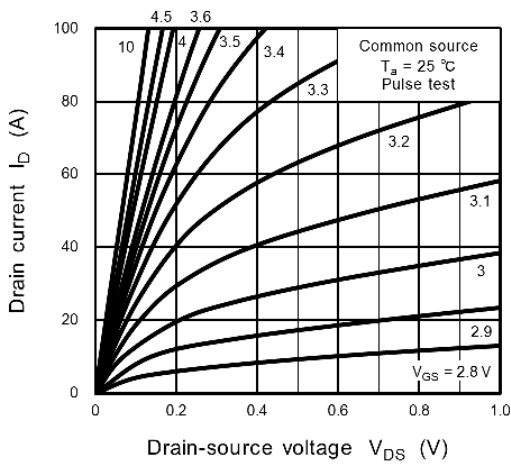


Fig. 8.1 $I_D - V_{DS}$

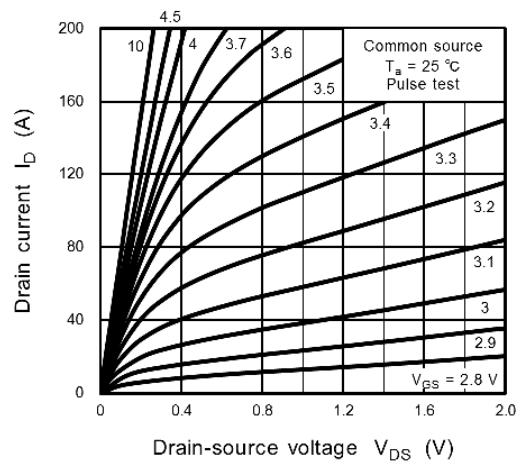


Fig. 8.2 $I_D - V_{DS}$

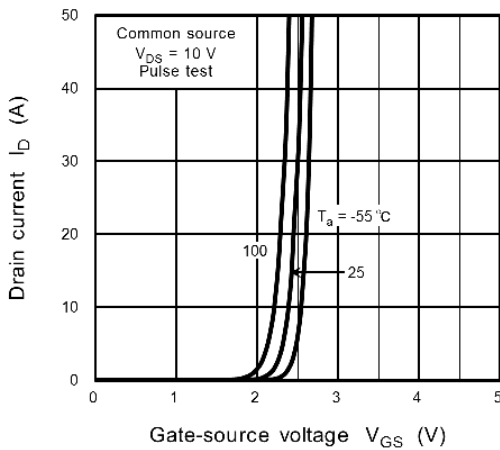


Fig. 8.3 $I_D - V_{GS}$

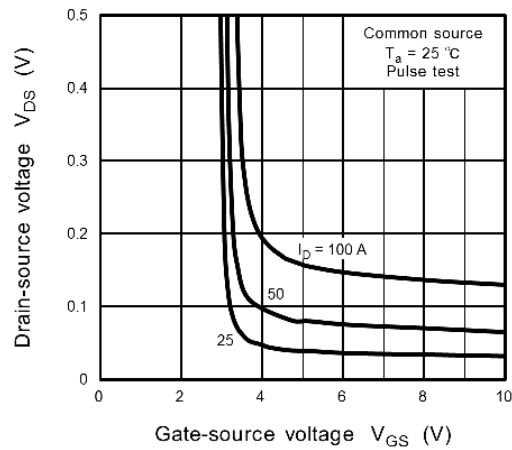


Fig. 8.4 $V_{DS} - V_{GS}$

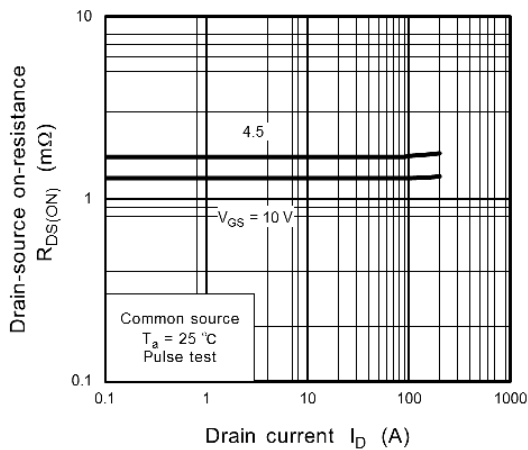


Fig. 8.5 $R_{DS(ON)} - I_D$

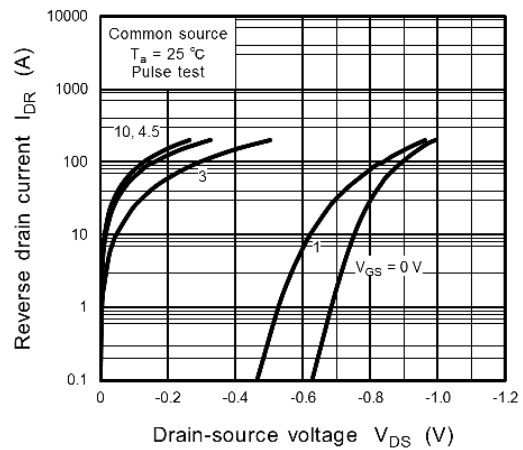


Fig. 8.6 $I_{DR} - V_{DS}$

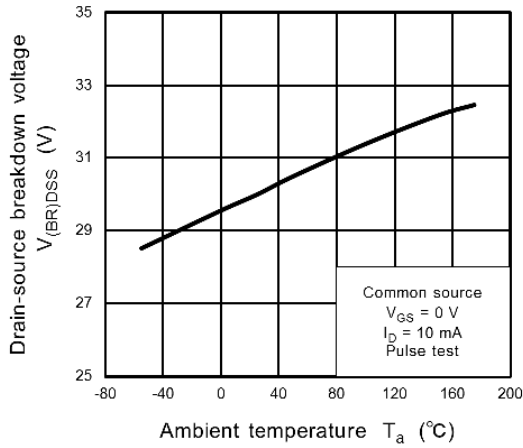


Fig. 8.7 $V_{(BR)DSS} - T_a$

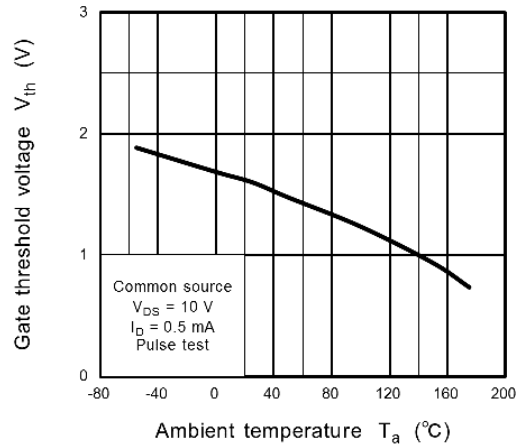


Fig. 8.8 $V_{th} - T_a$

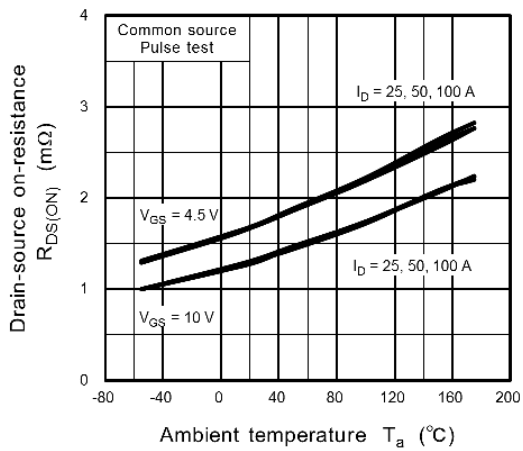


Fig. 8.9 $R_{DS(ON)} - T_a$

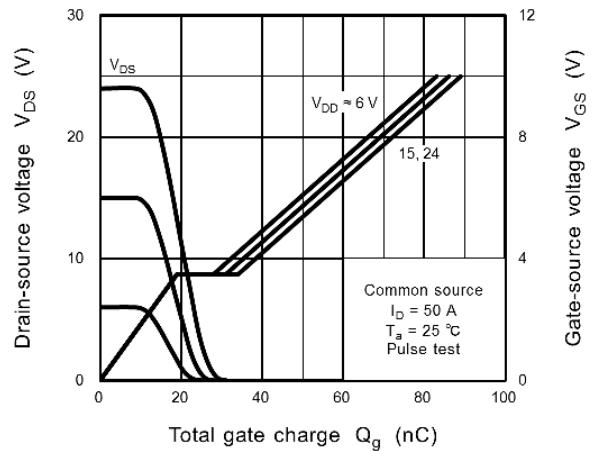


Fig. 8.10 Dynamic Input/Output Characteristics

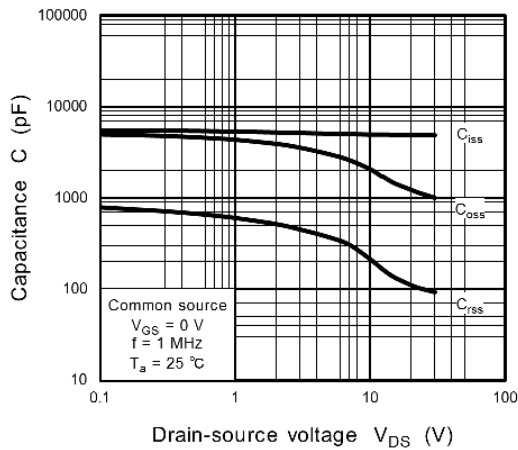


Fig. 8.11 Capacitance - V_{DS}

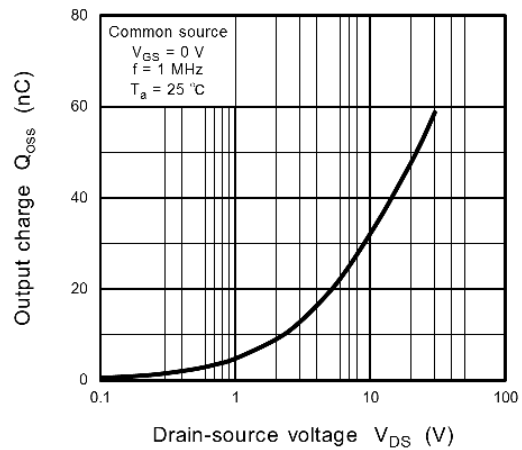


Fig. 8.12 $Q_{oss} - V_{DS}$

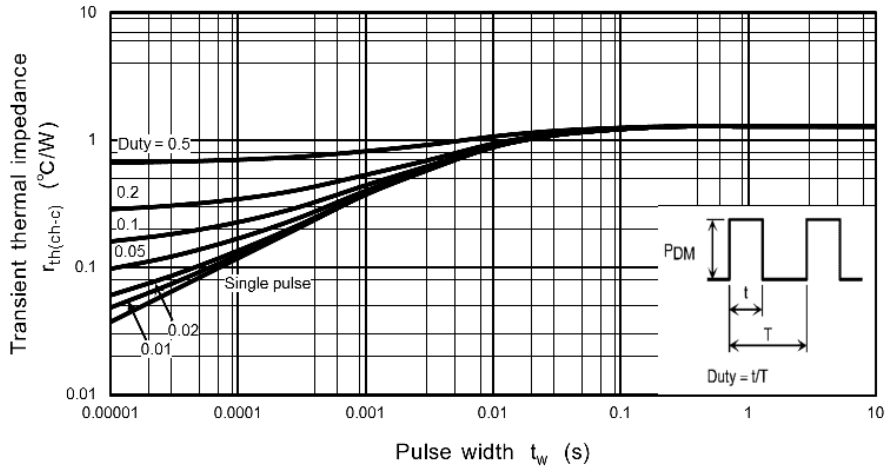


Fig. 8.13 $r_{th} - t_w$
(Guaranteed Maximum)

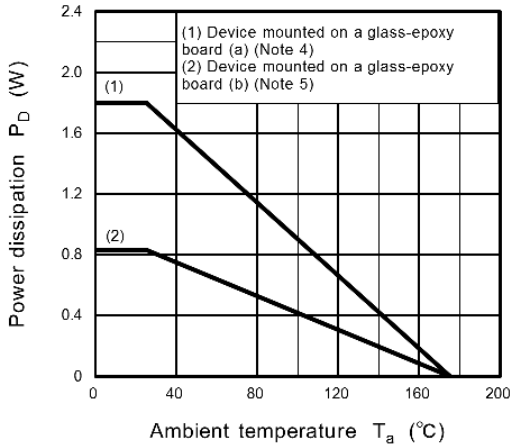


Fig. 8.14 $P_D - T_a$
(Guaranteed Maximum)

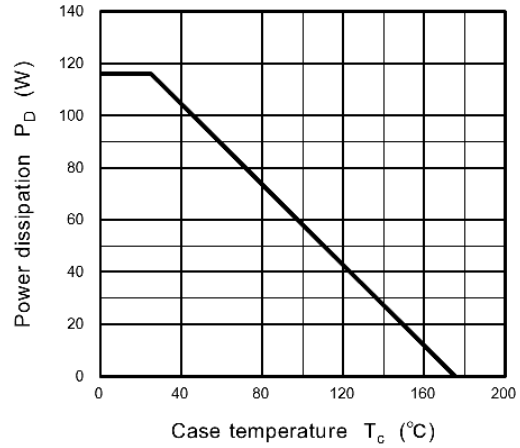


Fig. 8.15 $P_D - T_c$
(Guaranteed Maximum)

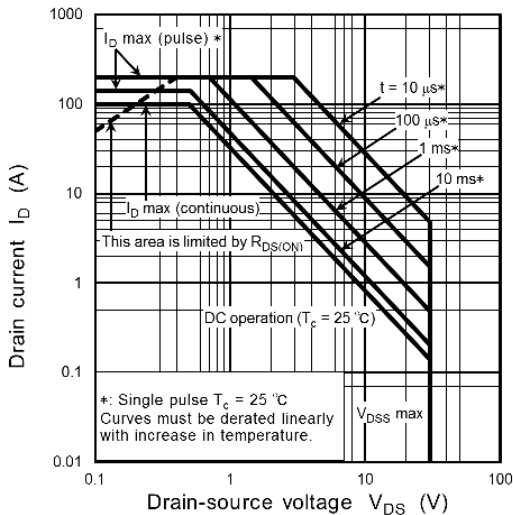
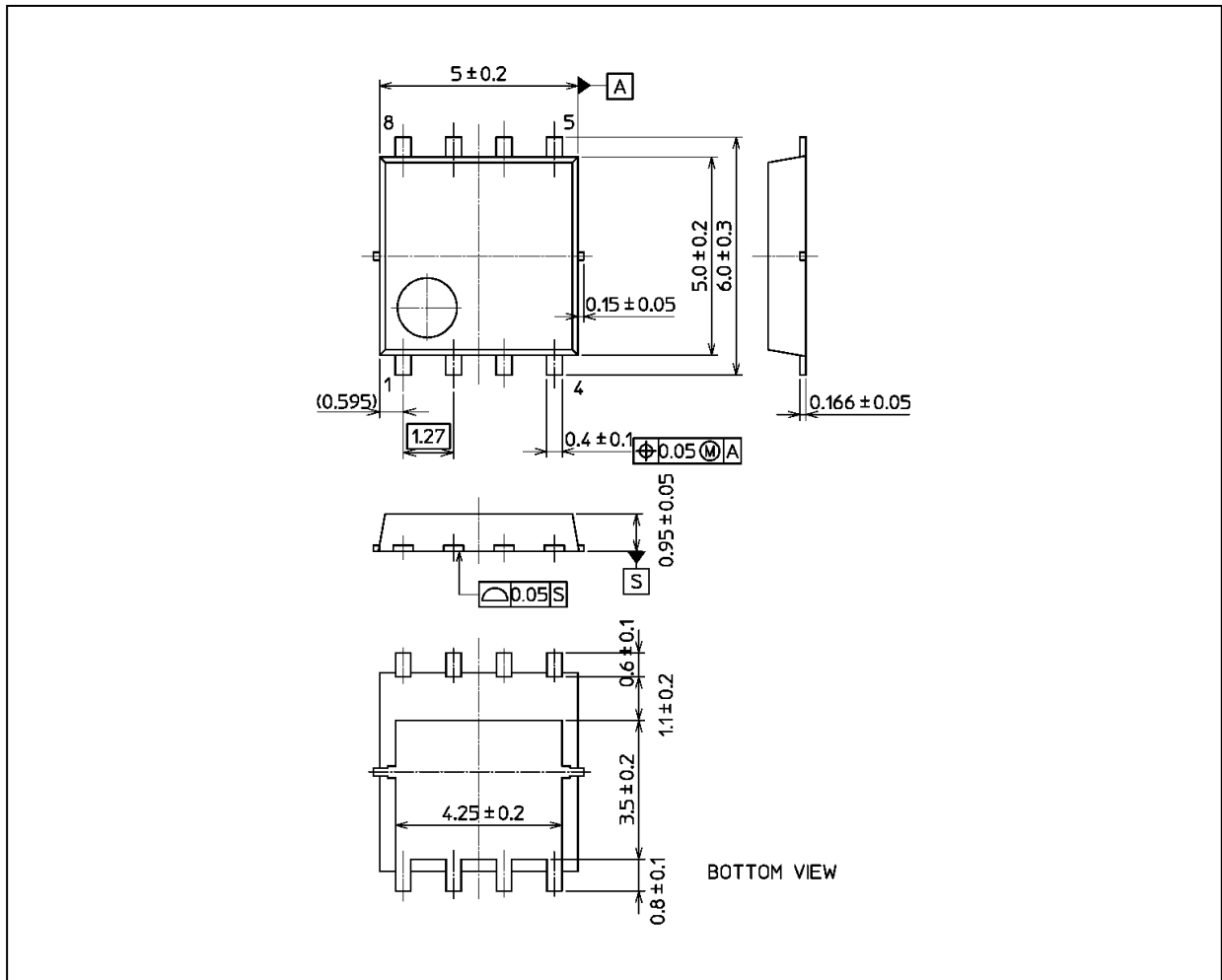


Fig. 8.16 Safe Operating Area
(Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

| Package Name(s) |
|-----------------------|
| TOSHIBA: 2-5Q1S |
| Nickname: SOP Advance |

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